TOSHIBA THYRISTOR SILICON PLANAR TYPE

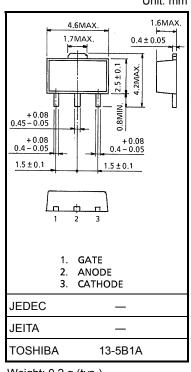
USF05G49

LOW POWER SWITCHING AND CONTROL **APPLICATIONS**

- Repetitive Peak Off-State Voltage : VDRM = 400 V Repetitive Peak Reverse Voltage : VRRM = 400 V
 - : IT (AV) = 500 mA
- Average On–State Current

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	V _{DRM} V _{RRM}	400	V	
Non-Repetitive Peak Reverse Voltage (Non-Repetitive<5ms, Tj = 0~125°C)	V _{RSM}	500	V	
Average On-State Current (Half Sine Waveform)	I _{T (AV)}	500	mA	
R.M.S On-State Current	I _{T (RMS)}	800	mA	
Peak One Cycle Surge On-State Current (Non-Repetitive)	I _{TSM}	9 (50Hz)	A	
		10 (60Hz)		
I ² t Limit Value	l ² t	0.4	A ² s	
Critical Rate of Rise of On-State Current (Note 1)	di / dt	10	A / µs	
Peak Gate Power Dissipation	P _{GM}	0.1	W	
Average Gate Power Dissipation	P _{G(AV)}	0.01	W	
Peak Forward Gate Voltage	V _{FGM}	3.5	V	
Peak Reverse Gate Voltage	V _{RGM}	-5	V	
Peak Forward Gate Current	I _{GM}	125	mA	
Junction Temperature	Тj	-40~125	°C	
Storage Temperature Range	T _{stg}	-40~125	°C	

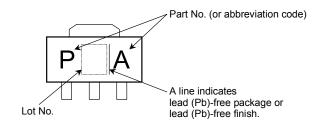


Weight: 0.2 g (typ.)

Should be used with Note: gate resistance as shown below. ANODE GATE C $R_{GK} = 1k\Omega$ CATHODE or Less \cap

Note 1: di / dt Test condition: i_G = 5mA, t_{gw} = 10µs, t_{gr} ≤250ns

MARKING

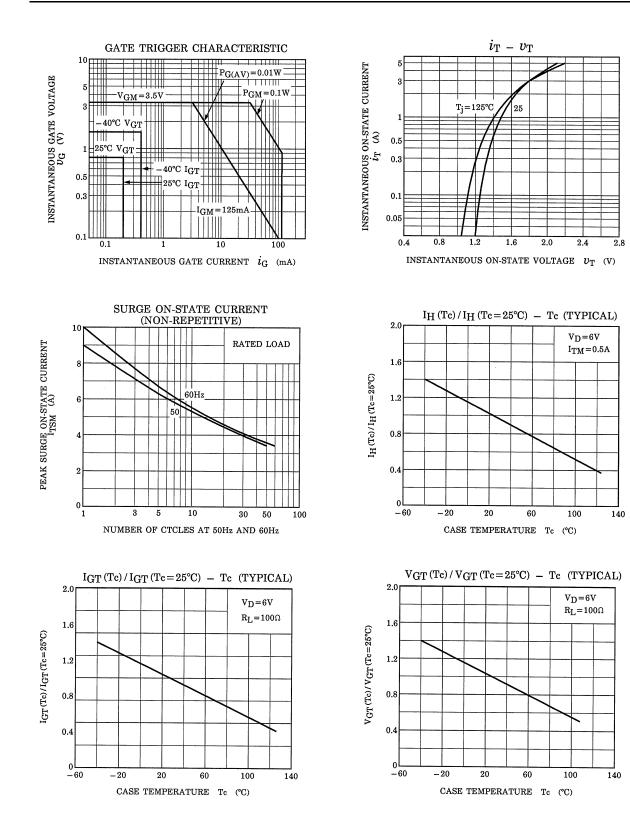


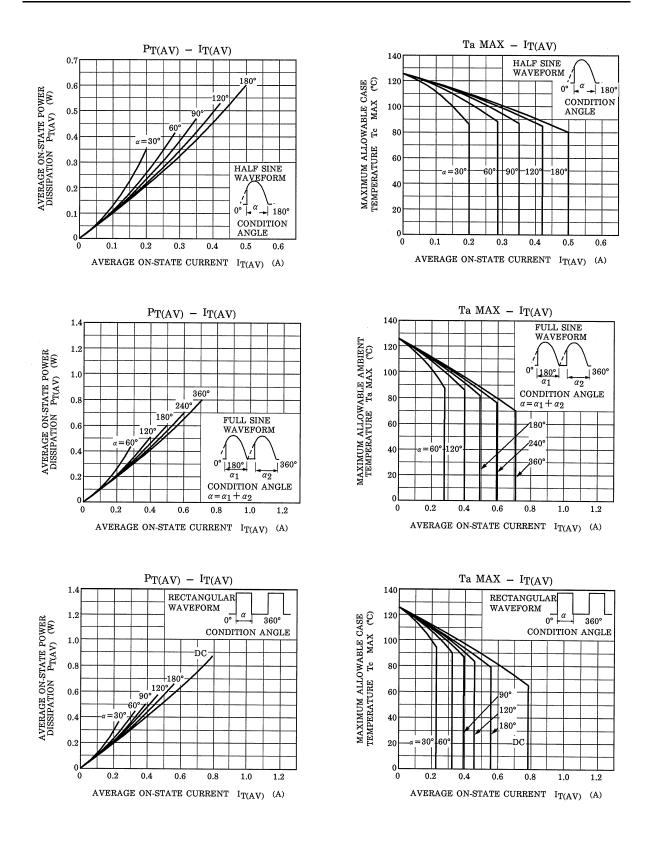
Unit: mm

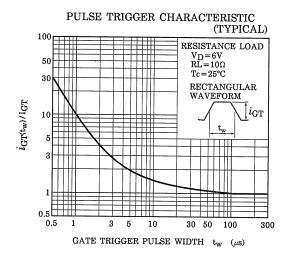
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

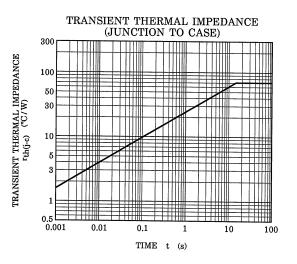
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I _{DRM} I _{RRM}	V _{DRM} = V _{RRM} = Rated	_	_	10	μΑ
Peak On-State Voltage	V _{TM}	I _{TM} = 1A		_	1.5	V
Gate Trigger Voltage	V _{GT}	$V_{\rm D} = 6V, R_{\rm I} = 100\Omega$		_	0.8	V
Gate Trigger Current	I _{GT}	$R_{GK} = 1k\Omega^{-1}$	_	_	200	μA
Holding Current	Ι _Η	I_{TM} = 500mA, V _D = 6V R _{GK} = 1kΩ	_	_	6	mA
Critical Rate of Rise of Off-State Voltage	d _v / dt	V _{DRM} = Rated, R _{GK} = 1kΩ Exponential Rise	_	200	_	V / µs
Gate Tum-On Time	t _{gt}	V_D = Rated, i _G = 5mA R _{GK} = 1kΩ	_	_	1.5	μs
Thermal Resistance	R _{th(j−a)}	Junction to Ambient	—	—	70	°C/W

Note: Thermal Resistance Test Condition Use 0.6×30×30mm Alumina Plate









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